

### **Features**

- Low On-Resistance
  - $25m\Omega @ V_{GS} = 4.5V$
  - 29mΩ @ V<sub>GS</sub> = 2.5V •
  - $36m\Omega @ V_{GS} = 1.8V$ •
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- ESD Protected Up To 2kV
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability



DMG6968U

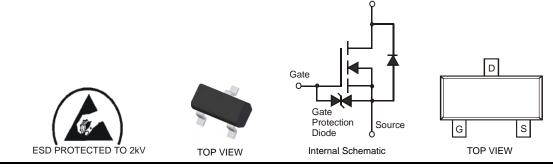
#### N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminals Connections: See Diagram Below
- Marking Information: See Page 4
- Ordering Information: See Page 4

Drain

Weight: 0.008 grams (approximate)



### **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

Characte	eristic		Symbol	Value	Units		
Drain-Source Voltage			V <sub>DSS</sub>	20	V		
Gate-Source Voltage			V <sub>GSS</sub>	±12	V		
Continuous Drain Current (Note 3)	nuous Drain Current (Note 3)Steady State $T_A = 25^{\circ}C$ $T_A = 70^{\circ}C$		lo	6.5 5.2	А		
Pulsed Drain Current			I <sub>DM</sub>	30	А		

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	PD	0.81	W
Thermal Resistance, Junction to Ambient $@T_A = 25^{\circ}C$	R <sub>0JA</sub>	157	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

Notes:

1. No purposefully added lead.

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
Device mounted on FR-4 PCB with minimum recommended pad layout.

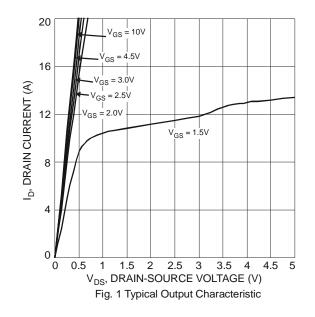


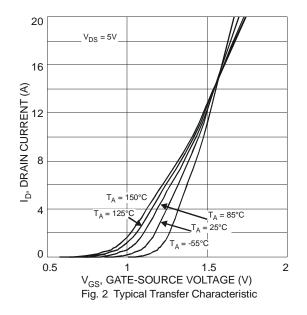
## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 4)									
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	20	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$		
Zero Gate Voltage Drain Current	$T_J = 25^{\circ}C$	IDSS	_	_	1.0	μΑ	$V_{DS} = 20V, V_{GS} = 0V$		
Gate-Source Leakage		I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 10V, V_{DS} = 0V$		
Gate-Source Breakdown Voltage		BV <sub>SGS</sub>	±12	-	-	V	$V_{DS} = 0V, I_{G} = \pm 250 \mu A$		
ON CHARACTERISTICS (Note 4)									
Gate Threshold Voltage		V <sub>GS(th)</sub>	0.5		0.9	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$		
			_	21	25		$V_{GS} = 4.5V, I_D = 6.5A$		
Static Drain-Source On-Resistance		R <sub>DS (ON)</sub>		23	29	mΩ	$V_{GS} = 2.5V, I_D = 5.5A$		
		. ,		28	36		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 3.5A		
Forward Transfer Admittance	Y <sub>fs</sub>	_	8	_	S	$V_{DS} = 10V, I_{D} = 5A$			
DYNAMIC CHARACTERISTICS							÷		
Input Capacitance			_	151		pF	N 40X X 0X		
Output Capacitance		Coss	_	91		pF	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 0V f = 1.0MHz		
Reverse Transfer Capacitance		C <sub>rss</sub>	_	32	_	pF			
Total Gate Charge	Qg	_	8.5	_	nC				
Gate-Source Charge		Q <sub>qs</sub>	_	1.6		nC	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 6.5A		
Gate-Drain Charge	Q <sub>gd</sub>	_	2.8	_	nC				
Turn-On Delay Time	t <sub>D(on)</sub>	_	54		ns				
Turn-On Rise Time	tr	_	66		ns	$V_{DD} = 10V, V_{GS} = 4.5V,$			
Turn-Off Delay Time	t <sub>D(off)</sub>	_	613	—	ns	$R_{L} = 10\Omega, R_{G} = 6\Omega, I_{D} = 1A$			
Turn-Off Fall Time	t <sub>f</sub>	_	205	_	ns	1			

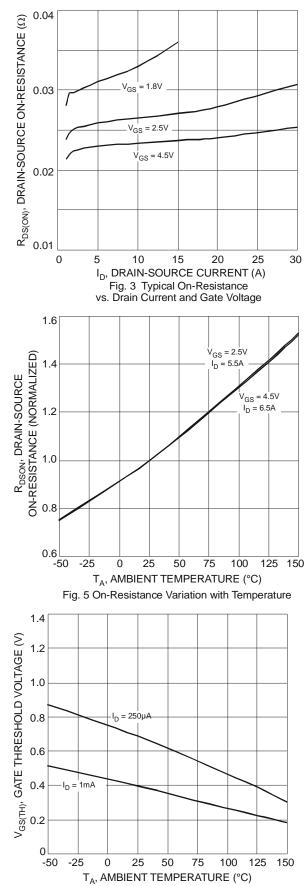
Notes:

4. Short duration pulse test used to minimize self-heating effect.

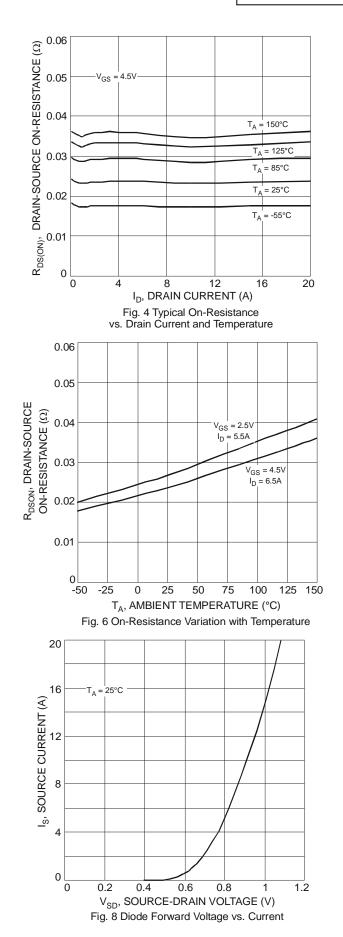






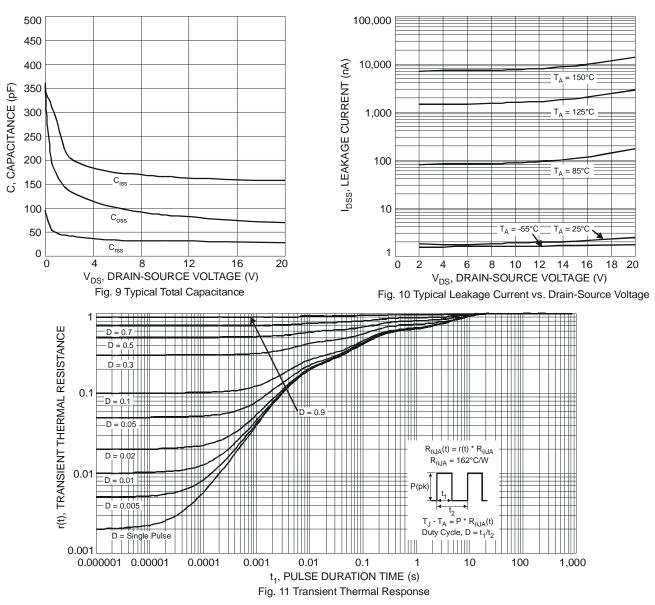






DMG6968U Document number: DS31738 Rev. 3 - 2



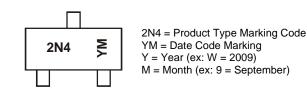


## Ordering Information (Note 5)

Part Number	Case	Packaging
DMG6968U-7	SOT-23	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

### **Marking Information**

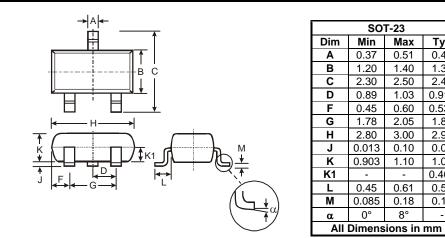


#### Date Code Key

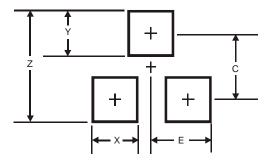
Date Code Rey												
Year	2009	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Y	2	2	А		В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## **Package Outline Dimensions**



# **Suggested Pad Layout**



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35

Тур

0.40

1.30

2.40

0.915

0.535

1.83

2.90

0.05

1.00

0.400

0.55

0.11

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